

## T1610H

Datasheet - production data

## 16 A Triac, high temperature and logic level



### Features

- Junction temperature up to 150 °C max.
- Logic level gate current: 10 mA
- Repetitive peak off-state voltage: 600 V
- High I<sub>TSM</sub>
- High thermal cycling performance

## Applications

- Electric heater
- Water heater, room heater
- Coffee machine
- Hand dryer
- Thermostat

### Description

This clip technology Triac has very high thermal cycling performance, and the design structure presents a higher  $I_{TSM}$ . The 150 °C maximum junction temperature of this device offers easier thermal management. Its 10 mA gate current offers direct drive from a microcontroller, mainly for resistive load control.

#### Table 1. Device summary

Order code	Package	V <sub>DRM</sub> , V <sub>RRM</sub>	I <sub>GT</sub>	I <sub>T(RMS)</sub>
T1610H-6T	TO-220AB	600 V	10 mA	16 A

This is information on a product in full production.

## 1 Characteristics

Symbol	Parameter		Value	Unit
I <sub>T(RMS)</sub>	On-state rms current (180° conduction angle)	T <sub>c</sub> = 133 °C	16	А
I	Non repetitive surge peak on-state current, T <sub>i</sub> initial = 25 °C	t <sub>p</sub> = 16.7 ms	168	А
ITSM	Non repetitive surge peak on-state current, $T_j$ initial = 25° C		160	А
l²t	I <sup>²</sup> t Value for fusing	t <sub>p</sub> = 10 ms	169	A²s
dl/dt	Critical rate of rise of on-state current, $I_G$ = 2 x $I_{GT}, tr \leq$ 100 ns	F = 60 Hz	100	A/µs
V <sub>DRM</sub> , V <sub>RRM</sub>	Repetitive peak off-state voltage	T <sub>j</sub> = 150 °C	600	V
V <sub>DSM</sub> , V <sub>RSM</sub>	Non repetitive peak off-state voltage	t <sub>p</sub> = 10 ms	700	V
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	4	А
P <sub>GM</sub>	Peak gate power dissipation	t <sub>p</sub> = 20 μs	10	W
P <sub>G(AV)</sub>	Average gate power dissipation		1	W
T <sub>stg</sub>	Storage junction temperature range		-40 to +150	°C
Тj	Operating junction temperature range			
Τ <sub>L</sub>	Lead temperature for soldering during 10 s			°C

## Table 2. Absolute maximum rating (T<sub>j</sub> = 25 °C, unless otherwise specified)

### Table 3. Electrical characteristics ( $T_j$ = 25 °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value	Unit	
1	V = 12 V P = 22 O		1 - 11 - 111	MIN.	0.5	mA
$I_{GT}$ $V_D = 12 V, R_L = 33 \Omega$				MAX.	10	mA
V <sub>GT</sub>	$V_D$ = 12 V, RL = 33 $\Omega$		1 - 11 - 111	MAX.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 150 \text{ °C}$	-    -	MIN.	0.2	V	
Ι <sub>Η</sub>	I <sub>T</sub> = 500 mA, gate open	-	MAX.	15	mA	
١L	I <sub>G</sub> = 1.2 I <sub>GT</sub>		-    -	MAX.	30	mA
dV/dt	$V_{D} = 67\% \times V_{DRM}, V_{RRM}, gate open$	$V_D = 67\% \times V_{DRM}, V_{RRM}$ , gate open $T_j = 150 \text{ °C}$		MIN.	100	V/µs
(dl/dt)c	(dV/dt)c = 0.1 V/µs	T = 150 °C	-	MIN.	8.5	A/ms
(ui/ut)c	$T_j = 150 \text{ °C}$		-	IVIIIN.	3	A/1115
t <sub>gt</sub>	$I_{TM}$ = 13 A, V <sub>D</sub> = 400 V, I <sub>G</sub> = 100 mA, dI <sub>G</sub> /dt = 100 mA/μs, R <sub>L</sub> = 30 Ω		-	TYP.	2	μs



Symbol	Test conditions				Unit
V <sub>TM</sub>	I <sub>TM</sub> = 22.5 A, t <sub>p</sub> = 380 μs	T <sub>j</sub> = 25 °C		1.55	V
V <sub>to</sub>	Threshold voltage	T <sub>j</sub> = 150 °C		0.80	V
R <sub>d</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	MAX.	22	mΩ
I <sub>DRM,</sub>	$\mathcal{M} = \mathcal{M}$	T <sub>j</sub> = 25 °C		5	μA
I <sub>RRM</sub>	$V_D = V_{DRM}, V_R = V_{RRM}$	T <sub>j</sub> = 150 °C		2	mA

Table 4. Static characteristics

#### Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	1.0	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (AC)	60	°C/W

## Figure 1. Maximum power dissipation versus average on-state current (full cycle)



Figure 2. On-state rms current versus case temperature (full cycle)



Figure 3. On-state rms current versus ambient temperature (free air convection)









# Figure 7. Relative variation of dV/dt immunity versus junction temperature (typical values)



Figure 9. Relative variation of critical rate of decrease of main current (di/dt)c versus reapplied (dV/dt)c





Figure 8. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature (typical values)



Figure 10. Surge peak on-state current versus number of cycles





Figure 11. Non repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms, and corresponding value of l<sup>2</sup>t











## 2 Package information

- Epoxy meets UL94, V0
- Recommended torque value: 0.4 to 0.6 N·m

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Figure 14. TO-220AB dimension definitions



			Dime	nsions		
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14		1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М		2.60			0.102	

Table 6. TO-220AB dimension values



## **3** Ordering information



Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T1610H-6T	T1610H-6T	TO-220AB	2.3	50	Tube

## 4 Revision history

Table 8. Documer	t revision history
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Date	Revision	Changes
31-May-2013	1	First issue.



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